

Features

- Trench Power LV MOSFET Technology
- High Density Cell Desihn for Low $R_{DS(on)}$
- Moisture Sensitivity Level 1
- Halogen Free . "Green" Device ^(Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

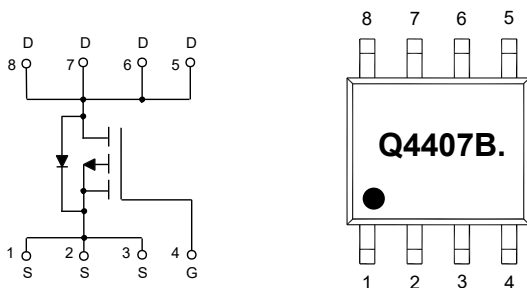
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 70°C/W Junction to Ambient ^(Note 2)

Parameter	Symbol	Rating	Unit	
Drain-Source Voltage	V_{DS}	-30	V	
Gate-Source Voltlage	V_{GS}	±25	V	
Continuous Drain Current	I_D	$T_A=25^\circ\text{C}$	-12	A
		$T_A=100^\circ\text{C}$	-7.6	A
Pulsed Drain Current ^(Note 3)	I_{DM}	-48	A	
Single Pulse Avalanche Energy ^(Note 4)	E_{AS}	90	mJ	
Total Power Dissipation ^(Note 5)	P_D	1.8	W	

Note:

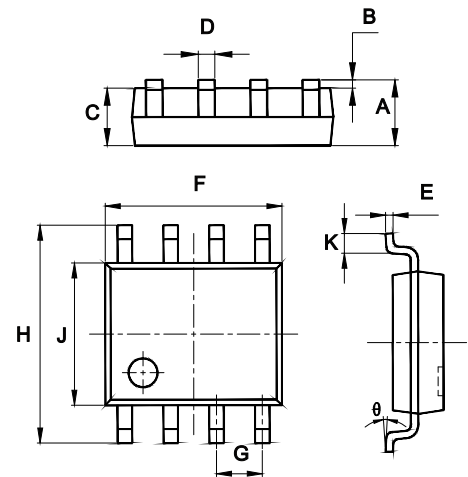
1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_A = 25^\circ\text{C}$.
3. Repetitive rating; pulse width limited by max. junction temperature.
4. P_D is based on max. junction temperature, using junction to ambient thermal resistance.
5. $T_J=25^\circ\text{C}$, $V_{DD}=-20\text{V}$, $V_{GS}=10\text{V}$, $L=0.5\text{mH}$

Internal Structure and Marking Code



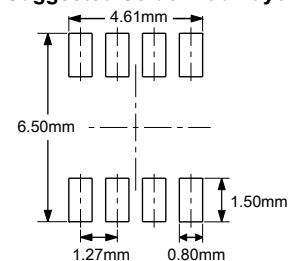
P-CHANNEL MOSFET

SOP-8



DIM	DIMENSIONS				NOTE
	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	0.053	0.069	1.35	1.75	
B	0.004	0.010	0.10	0.25	
C	0.053	0.061	1.35	1.55	
D	0.013	0.020	0.33	0.51	
E	0.007	0.010	0.17	0.25	
F	0.185	0.200	4.70	5.10	
G	0.050		1.270		TYP.
H	0.228	0.244	5.80	6.20	
J	0.150	0.157	3.80	4.00	
K	0.016	0.050	0.40	1.27	
θ	0°	8°	0°	8°	

Suggested Solder Pad Layout



Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-30			V
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 25V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-30V, V_{GS}=0V$			-1	μA
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-1.2	-1.8	-2.8	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=-20V, I_D=-12A$		9	10.5	m Ω
		$V_{GS}=-10V, I_D=-12A$		10.2	12.5	
		$V_{GS}=-6V, I_D=-10A$		12.3	16.5	
		$V_{GS}=-4.5V, I_D=-10A$		16	25	
Gate Resistance	R_g	F=1 MHz, Open drain		7.3		Ω
Diode Characteristics						
Continuous Body Diode Current	I_S				-12	A
Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=-12A$			-1.2	V
Reverse Recovery Time	t_{rr}	$I_F=-12A, dI_F/dt=100A/\mu s$		23.5		ns
Reverse Recovery Charge	Q_{rr}			10.6		nC
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS}=-15V, V_{GS}=0V, f=1MHz$		2478		pF
Output Capacitance	C_{oss}			307		
Reverse Transfer Capacitance	C_{rss}			271		
Total Gate Charge	Q_g	$V_{DS}=-15V, V_{GS}=-10V, I_D=-12A$		44.5		nC
Gate-Source Charge	Q_{gs}			6.6		
Gate-Drain Charge	Q_{gd}			9		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=-10V, V_{DD}=-15V, I_D=-1A, R_{GEN}=2.5\Omega$		11		ns
Turn-On Rise Time	t_r			6.5		
Turn-Off Delay Time	$t_{d(off)}$			82.5		
Turn-Off Fall Time	t_f			38.5		

Curve Characteristics

Fig. 1 - Typical Output Characteristics

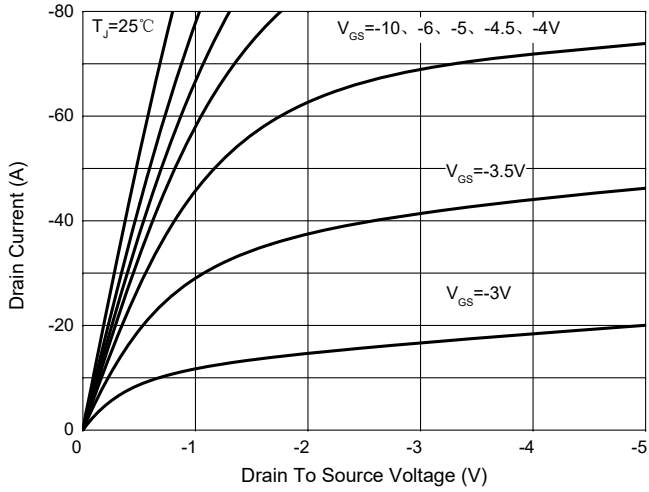


Fig. 2 - Transfer Characteristics

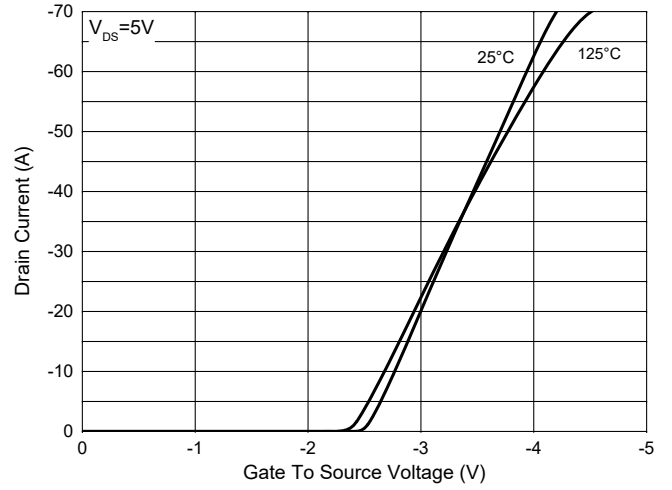


Fig. 3 - $R_{DS(ON)} - V_{GS}$

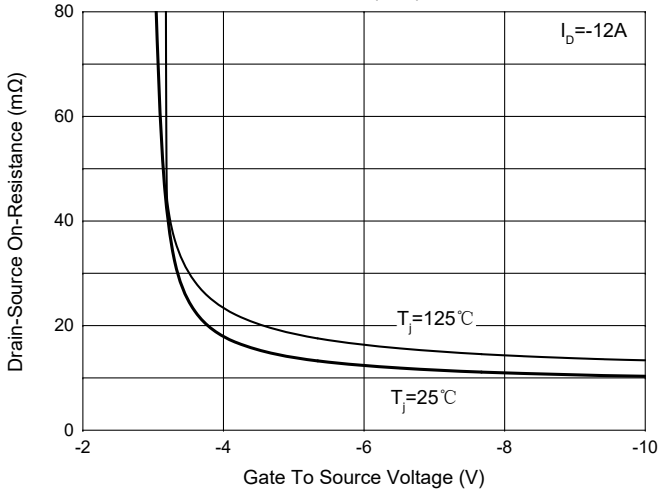


Fig. 4 - $R_{DS(ON)} - I_D$

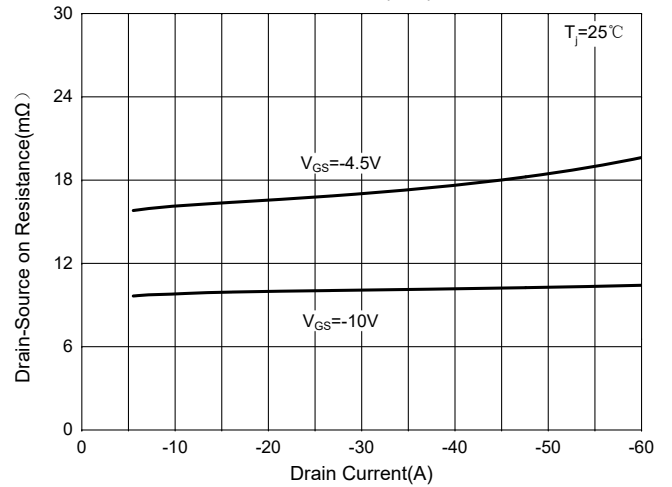


Fig. 5 - Capacitance Characteristics

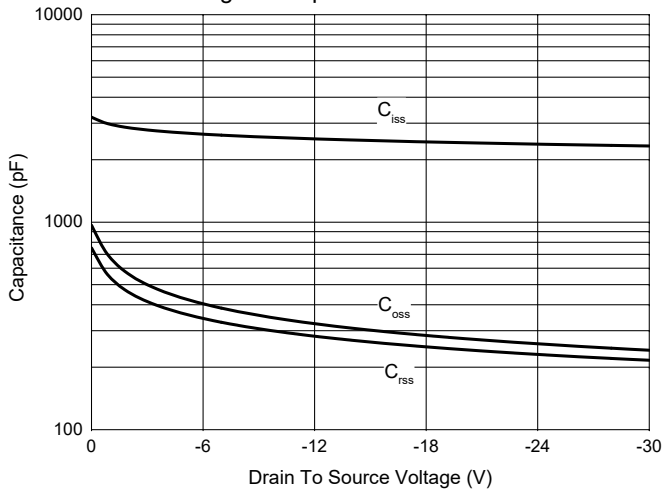
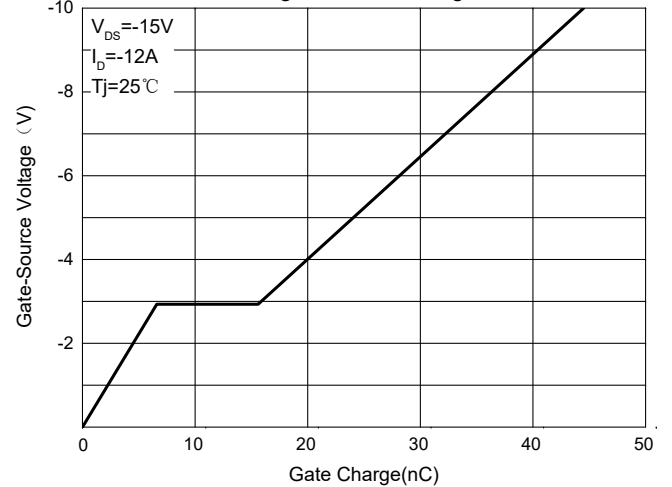


Fig. 6 - Gate Charge



Curve Characteristics

Fig. 7 - Normalized Threshold voltage

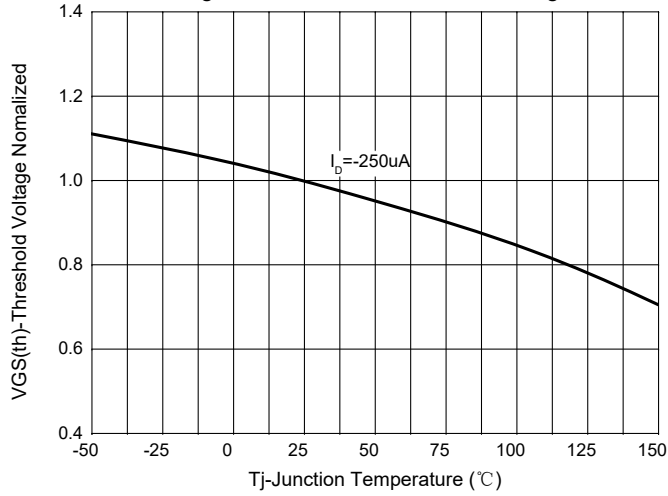


Fig.8-Normalized On Resistance Characteristics

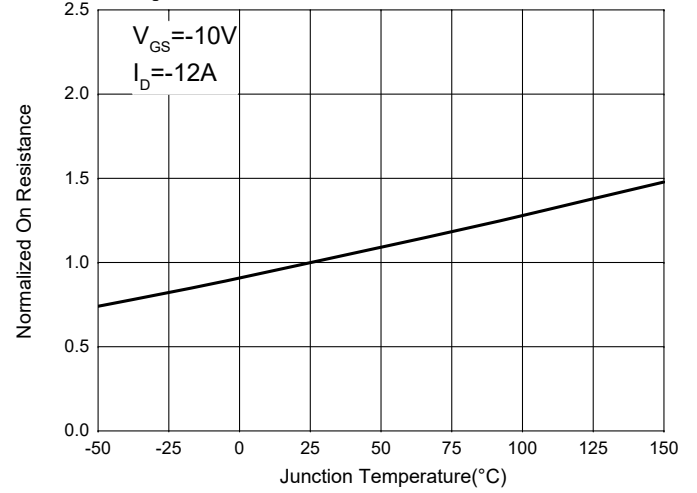


Fig.9 - $I_S - V_{SD}$

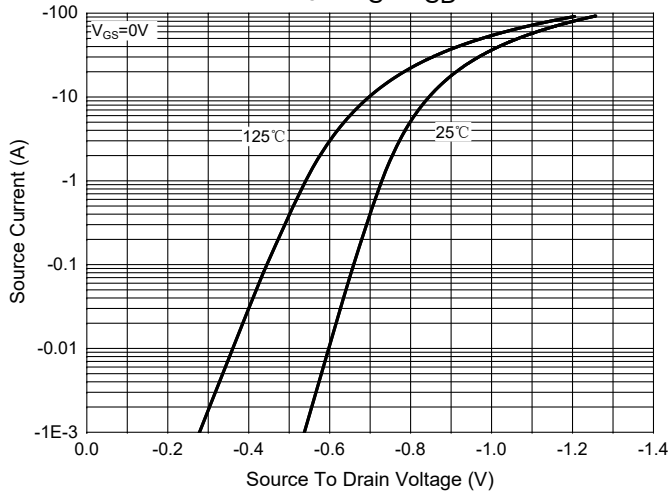


Fig. 10 - Current Dissipation

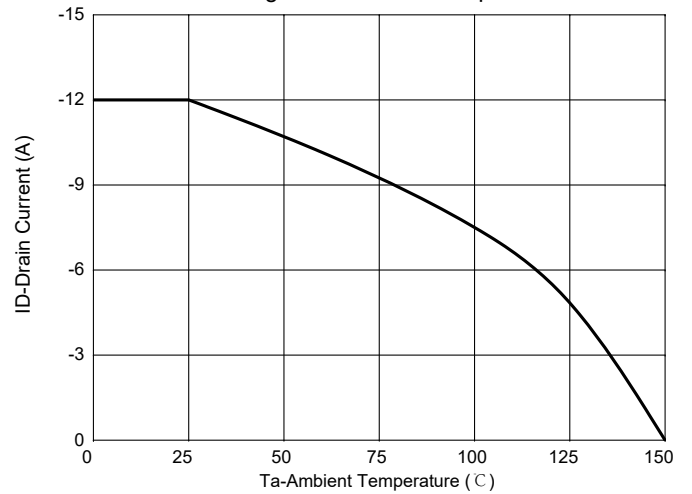
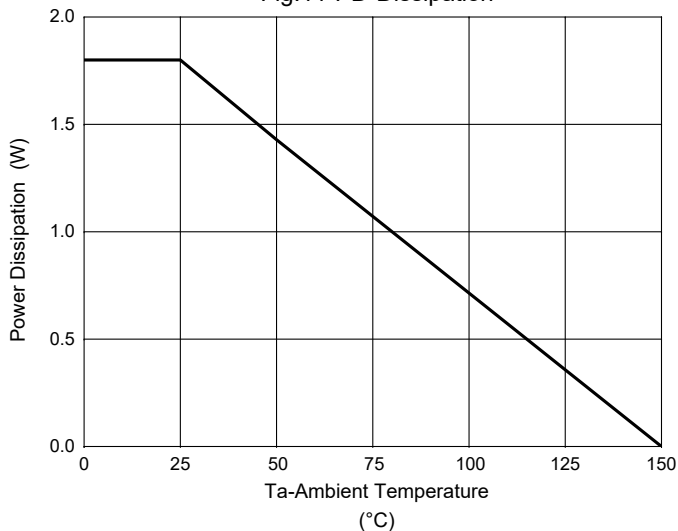


Fig.11-PD-Dissipation



Curve Characteristics

Fig. 12 - Safe Operation Area

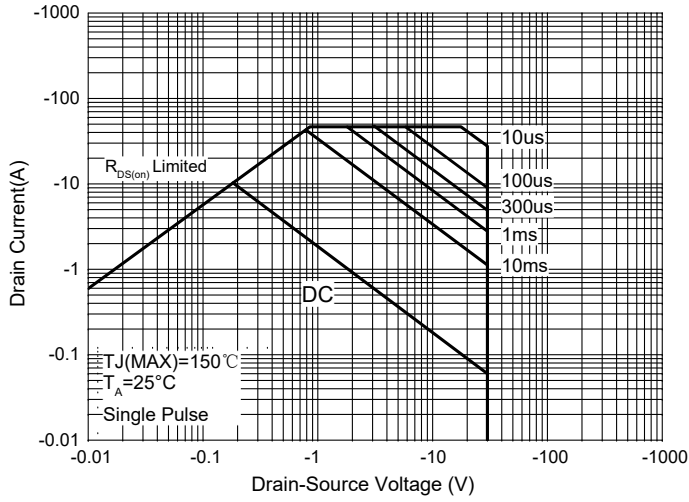
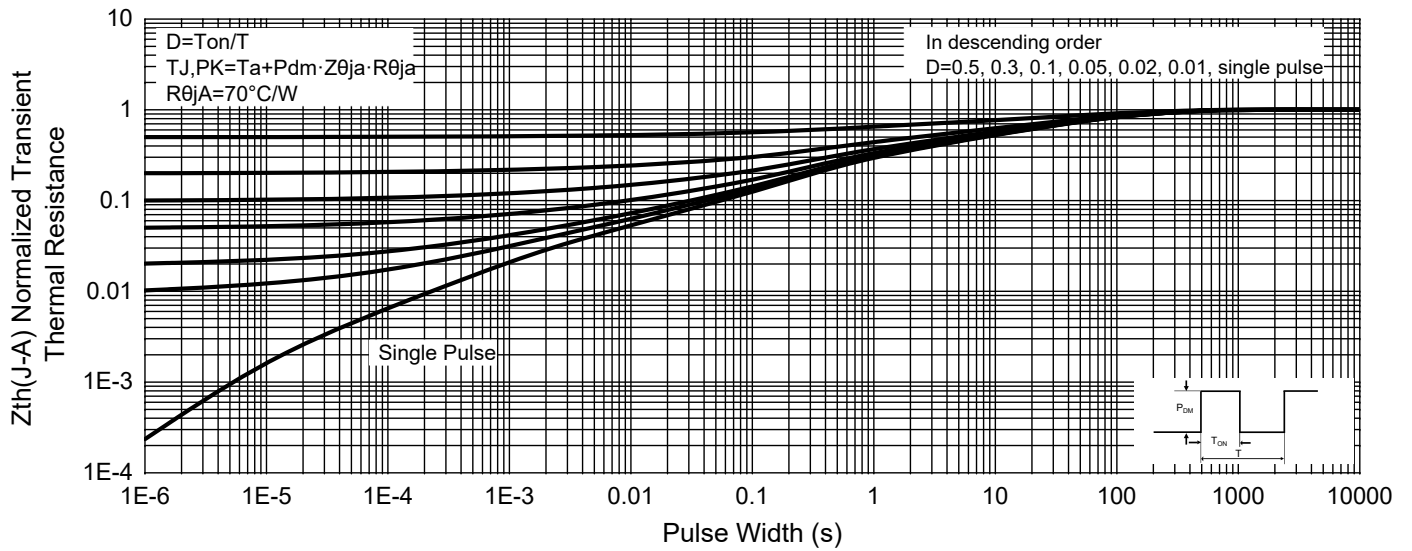


Fig. 13 - Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 4Kpcs/Reel

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